Short Note

## Num erical Studies of Fano Resonance in Quantum dots Embedded in AB Rings

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## KEYW ORDS: quantum dot, AB ring, Fano resonance, phase lapse, dephasing, resonant tunneling, Aharonov-Bohm e ect

In A haronov-Bohm (AB) rings with a quantum dot embedded in one arm, the Fano resonance has been observed recently.<sup>1)</sup> In previous works, the AB oscillation was reported in such system s, as a function of magnetic ux enclosed in the ring<sup>2,3)</sup> The AB oscillation is caused by the interference between the electronic wave passing through one arm and that through the other, as in a double-slit interferom eter. C om pared with the AB oscillation, the higher-order interference e ect between the two paths (a discrete level "<sub>0</sub> in the quantum dot and a continuum of states in the other arm) results in the Fano resonance.<sup>4)</sup> The conductance shows an asymm etric shape of the resonance,  $G / (e+q)^2 = (e^2 + 1)$ , with  $e = (" "_0) = ,$  where " is the energy of an incident electron (Ferm i energy) and is the line broadening.

The Fano resonance observed in the quantum -dot system s shows unique characters.<sup>1)</sup> (i) With increasing m agnetic ux, an asym m etric resonance-shape with negative q changes to that with positive q, via a symmetric resonance-shape. (ii) A round the center of resonance, the \phase" seems to change continuously in two-term inal set-ups, although the phase jum ps by in the AB oscillation observed by the two-term inalm easurem ent.<sup>2)</sup> (iii) The Fano resonance is observable only when the high coherence is kept in the whole system . These properties have not been fully understood in spite of several theoretical works including the electron-electron interaction in quantum dots.<sup>5{7)</sup> In this short note, we exam ine two m odels of non-interacting electrons. The merit of model (a) in Fig.1 is to obtain an exact expression for the resonance as a function of magnetic ux. The calculated results clearly explain the experimental ndings (i) and (iii). Regarding (iiii), we consider the dephasing e ect on the Fano resonance in model (b) by num erical calculations.

> (a) (b) lead L  $V_{L,i} O_{V,i} O_{R,i}$   $V_{R,i} O_{V,i} O_{$

Fig. 1. Twom odels we study for the transport properties of quantum dots embedded in AB rings.

In model (a), the magnetic ux enclosed in the ring

is taken into account by the phase factor of the direct tunnel-coupling, W , between leads L and R.W e obtain the conductance in an analytical form. In the case of single level ("\_0) in the quantum dot, the conductance is written as an extended Fano form,  $^{8)}$ 

$$G = \frac{2e^2}{h} \frac{4^2}{(1+2)^2} \frac{\dot{p}+q\dot{p}}{e^2+1};$$
 (1)

with a complex parameter

$$q = \frac{V_L V_R}{V_L^2 + V_R^2} \frac{1 + 2}{1 + 2} \frac{1}{1 + 2} \cos \text{ isin } : (2)$$

W and e = (" $"_{0}()) = ~, where$ Here, = is the density of states in the leads,  $"_0() = "_0$  $\frac{1}{1+2}$  (2 V<sub>L</sub>V<sub>R</sub>) cos and ~ = = (1 + 2) with being  $(V_{L}^{2} + V_{R}^{2})$ . Parameter characterizes the strength of direct transmission between the leads (0 1).9)Figure 2 (upper panel) show sG as a function of "when = 0:3. With increasing (magnetic ux in the ring), an asymmetric line-shape of G (Req > 0 at = 0) changes to symmetric (Req = 0 at = =2) and to asymmetric (Req < 0 at = ), in accordance with the experim ental results m entioned above.

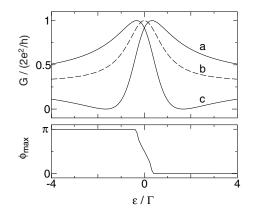


Fig. 2. The conductance (upper panel) and phase  $m_{ax}$  (lower panel), as functions of the Ferm i energy ", in model (a) with single level (" $_0 = 0$ ). = 0:3. In the upper panel, the magnetic ux is a, = 0; b, = =2; and c, = .

We de ne \phase" of the resonance as  $m_{ax}$ , the value of when G() is maximal. As shown in Fig.2 (lower panel),  $m_{ax}$  changes from to 0 rapidly but continuously with increasing ". Note that this does not contradict the Onsager's relation, G() = G(), in twoterm inal situations. In accordance with the relation, G

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in eq. (1) is a function of  $\cos ; G = F(\cos )$ . At the maximum of G,  $F^{0}(\cos ) \sin = 0$ . When the equation of  $F^{0}(\cos ) = 0$  has solutions,  $0 < _{max} < .0$  therewise  $_{max} = 0$  or , which is always the case of AB oscillation.<sup>2)</sup>

For more than one level in model (a), the conductance can be expressed in terms of the Green's functions (Appendix). The conductance G ( = 0) and  $m_{ax}$ are shown in Fig. 3, in the case of two levels with  $V_{L;1} = V_{R;1} = V_{L;2} = V_{R;2}$ . When  $V_{L;1}=V_{R;1}$  and  $V_{L;2}=V_{R;2}$  are in phase, two Fano resonances are asymm etric in the sam e direction. max changes continuously at both the resonances. Between them,  $m_{ax}$ bv jum psby (phase lapse). When  $V_{L;1}=V_{R;1}$  and  $V_{L;2}=V_{R;2}$ are out-of-phase, the Fano resonances are asymmetric in the opposite direction.  $m_{ax}$  changes by at one resonance and by at the other resonance. In this case, no phase lapse takes place.

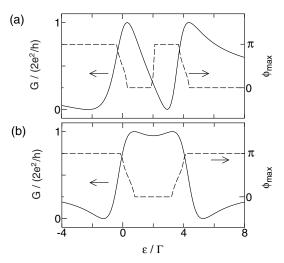


Fig. 3. The conductance G ( = 0) and phase  $_{m ax}$ , as functions of the Ferm i energy ", in model (a) with two levels ("<sub>1</sub> = 0, "<sub>2</sub> = 4). = 0:3. (a)  $V_{L;1} = V_{R;1} = V_{L;2} = V_{R;2}$ , whereas (b)  $V_{L;1} = V_{R;1} = V_{R;2} = V_{R;2}$ .

M odel (b) consists of one-dimensional perfect wires. The quantum dot is formed between two -functions (V  $_{\rm L}$  (x  $~x_{\rm L}$  ), V  $_{\rm R}$  (x  $~x_{\rm R}$  )), the electrochem ical potential of which is controlled by  $V_q$ . The ring is 1000A in radius. The dot size is L =  $x_R$   $x_L$  = 1000A and  $V_{L,R} = \sim^2 = (2m L)$  10, 15 (m = 0.067m). The dephasing e ect is taken into account on the upper arm phenom enologically; a part () of the current loses the phase information in virtual electrodes.<sup>10)</sup> W e evaluate the conductance num erically using the S-m atrix m ethod. The calculated results with = 1=2 are given in Fig. 4. The conductance as a function of  $eV_{\alpha}$  shows an asymmetric shape of resonance (solid line) or symmetric one (dotted line), depending on the magnetic ux enclosed in the ring.<sup>11)</sup> The amplitude of the resonance decreases as the dephasing e ect is enhanced ( is larger). The Fano resonance is clearly observed even with > 1=2, which indicates the robustness of the resonance. This seems against the experim ental results and should be attributable to the sim plicity of the model, e.g. disregarding the thickness of the wires.

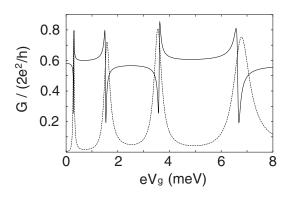


Fig. 4. The conductance as a function of  $eV_g$  in m odel (b). The energy levels are shifted by  $eV_g$  in the quantum dot, whereas the Ferm i level is xed. The dephasing rate is = 1=2. The magnetic ux in the ring is =(~=e) = 0 (solid line) and =2 (dotted line).

## Appendix: Calculations of conductance in model (a) with multilevel

The G reen's functions G  $_{\rm ij}$  ("), with i and j being level indices in the quantum dot, are given by

$$\begin{array}{c} X \\ [(" "_{i})_{ij} _{ij}]G_{jk}(") = _{ik}; \quad (A \cdot 1) \\ \\ i \\ j \\ i \\ j \\ i \\ i \\ \frac{1}{1 + 2} \quad i \quad (V_{L}; i V_{L}; j + V_{R}; i V_{R}; j) \\ \\ (e^{i} V_{L}; i V_{R}; j + e^{i} V_{R}; i V_{L}; j) : \quad (A \cdot 2) \end{array}$$

The T-m atrix between states in lead R and those in lead L is

$$I_{R,L} = \frac{1}{1+2} 4 W e^{i} + \frac{X}{ij} G_{ij} (") (W e^{i} _{ji} + V_{L,j} V_{R,i})^{5}$$
(A -3)

F inally the conductance is written as

$$G = \frac{2e^2}{h} (2 )^2 J_{R;L}^2$$
 (A -4)

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- 11) In one-dimensional quantum dots,  $V_{L,i}=V_{R,i}$  of a level is always out-of-phase with that of the next level.